NSN 5961-01-040-0095

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Inclosure Material: Metal Overall Length: Between 0.170 inches and 0.210 inches Terminal Length: Between 0.500 inches and 0.750 inches Overall Diameter: Between 0.209 inches and 0.230 inches Internal Configuration: Field effect

Electrode Internally-electrically Connected To Case:

Gate

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

30.0 drain to gate voltage and 30.0 drain to source voltage and 30.0 gate to source voltage

Current Rating Per Characteristic:

50.00 milliamperes gate current

Power Rating Per Characteristic:

500.0 milliwatts total power dissipation

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

81349-mil-s-19500/476 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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